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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="mailto:www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

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**FDS6679** 

FAIRCHILD

### 30 Volt P-Channel PowerTrench<sup>®</sup> MOSFET

#### **General Description**

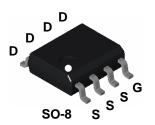
This P-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers, and battery chargers.

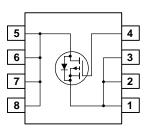
These MOSFETs feature faster switching and lower gate charge than other MOSFETs with comparable R<sub>DS(ON)</sub> specifications.

The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

#### **Features**

- $-13 \text{ A}, -30 \text{ V}. \text{ R}_{\text{DS(ON)}} = 9 \text{ m}\Omega @ \text{V}_{\text{GS}} = -10 \text{ V}$  $R_{DS(ON)} = 13 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$
- Extended  $V_{GSS}$  range (±25V) for battery applications
- High performance trench technology for extremely low R<sub>DS(ON)</sub>
- · High power and current handling capability





#### Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		-30	V
V <sub>GSS</sub>	Gate-Source Voltage		±25	V
I <sub>D</sub>	Drain Current – Continuous	(Note 1a)	-13	A
	- Pulsed		-50	
P <sub>D</sub>	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.2	
		(Note 1c)	1.0	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range		-55 to +175	°C
Therma	I Characteristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

#### Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
FDS6679	FDS6679	13"	12mm	2500 units

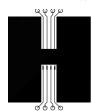
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FDS6679

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-30	İ		V
<u>ΔBV<sub>DSS</sub></u> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25°C		-23		mV/°C
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = -24 \text{ V},  V_{GS} = 0 \text{ V}$			-1	μA
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS} = \pm 25 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-1	-1.6	-3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to $25^{\circ}$ C		5		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$V_{GS} = -10 \text{ V},  I_D = -13 \text{ A}$ $V_{GS} = -4.5 \text{ V},  I_D = -11 \text{ A}$ $V_{GS} = -10 \text{ V}, I_D = -13 \text{ A}, T_J = 125^{\circ}\text{C}$		7.3 10 9.5	9 13 13	mΩ
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = -10 \text{ V}, \qquad V_{DS} = -5 \text{ V}$	-50			Α
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5 V$ , $I_{D} = -13 A$		44		S
Dynamic	c Characteristics					
Ciss	Input Capacitance	$V_{DS} = -15 V$ , $V_{GS} = 0 V$ ,		3939		pF
Coss	Output Capacitance	f = 1.0 MHz		972		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			498		pF
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = -15 V$ , $I_D = -1 A$ ,		19	34	ns
tr	Turn–On Rise Time	$V_{GS} = -10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		10	20	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			110	176	ns
t <sub>f</sub>	Turn–Off Fall Time			65	104	ns
Qq	Total Gate Charge	$V_{DS} = -15 \text{ V}, \qquad I_{D} = -13 \text{ A},$		71	100	nC
Q <sub>gs</sub>	Gate–Source Charge	$V_{GS} = -10 \text{ V}$		12		nC
Q <sub>gd</sub>	Gate–Drain Charge	1		15		nC
Drain-Se	ource Diode Characteristics	and Maximum Ratings				
Is	Maximum Continuous Drain–Source				-2.1	А
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_S = -2.1 A$ (Note 2)		-0.7	-1.2	V

Notes:

1.  $R_{\theta,JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta,CA}$  is guaranteed by design while  $R_{\theta,CA}$  is determined by the user's board design.



a) 50°C/W (10 sec) 62.5°C/W steady state when mounted on a 1in<sup>2</sup> pad of 2 oz copper

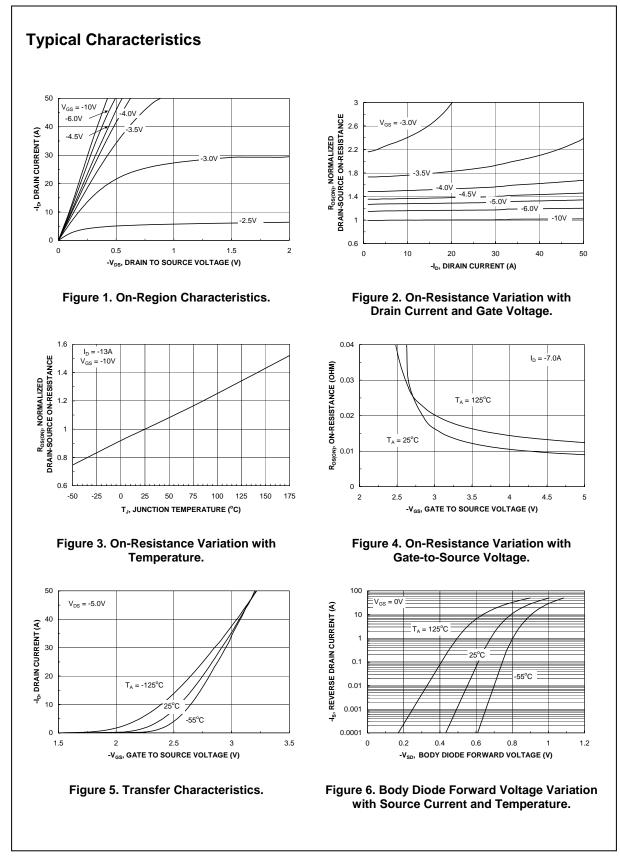


b) 105°C/W when mounted on a .04 in<sup>2</sup> pad of 2 oz copper

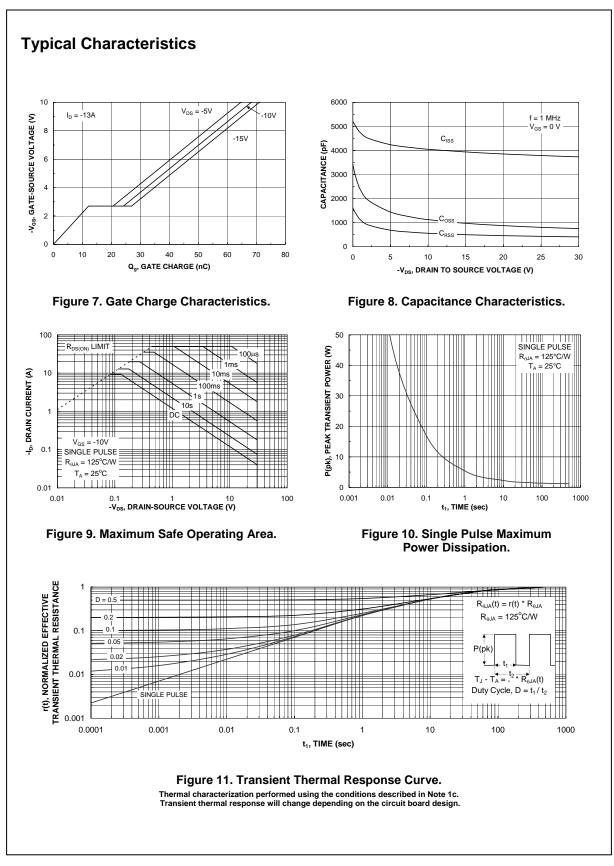
c) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 $\mu$ s, Duty Cycle < 2.0%



# FDS6679



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